



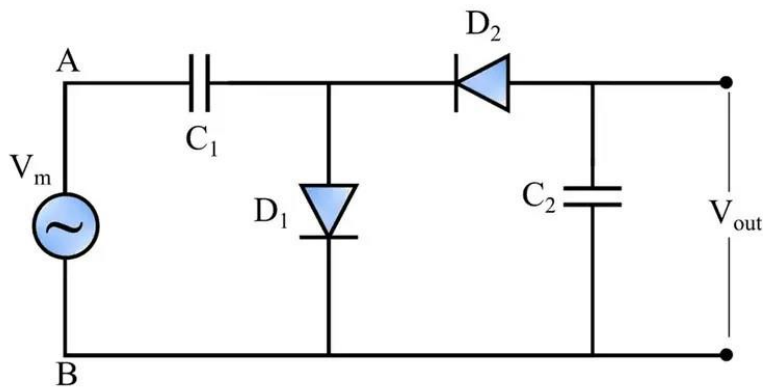
North South University

School of Engineering & Physical Sciences

EEE 111/ ETE 111 Analog Electronics-I

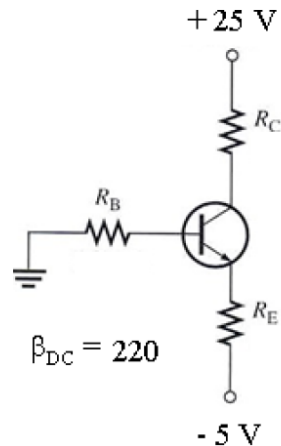
Assignment-1 (Full marks-100)

1. Explain semiconductor doping and provide a concise overview of majority and minority carriers in both p-type and n-type semiconductors. [CO1] [10]
2. Explain the operational principle of a full-wave rectifier and deduce the formula for the average output voltage. Furthermore, explore the feasibility of constructing a DC power supply using the full-wave rectifier's output. If feasible, what supplementary components would be required, and outline the circuit's functionality. [CO1] [10]
3. Suppose a sinusoidal input voltage with a peak value of V_m is applied to the following circuit. Sketch the output voltage waveform and describe the steps taken to attain this output voltage shape. [CO1] [20]



4. Determine the operating point (V_{CEQ} and I_{CQ}) of the transistor for the following conditions- [CO2] [20]

- (a) $R_B = 330\Omega$, $R_E = 3K\Omega$, $R_C = 1.6K\Omega$
 (b) $R_B = 150\Omega$, $R_E = 1K\Omega$, $R_C = 1.6K\Omega$
 (c) $R_B = 150\Omega$, $R_E = 500\Omega$, $R_C = 4 K\Omega$



5. Calculate I_{CQ} and V_{CEQ} for the following network where the value of $R_E =$ [CO2] [40]
 Sum of the digits of your student ID $\times 20$. Also, the value of $V_{CC} =$
 Sum of the digits of your student ID $\times \frac{2}{3}$. [Example: R_S for ID
 2131951643 = $(2 + 1 + 3 + 1 + 9 + 5 + 1 + 6 + 4 + 3) \times 20 =$
 700Ω ; $V_{CC} = (2 + 1 + 3 + 1 + 9 + 5 + 1 + 6 + 4 + 3) \times \frac{2}{3} =$
 23.33 V].

